

2N4402



PNP General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	40	V
V _{EBO}	Emitter-Base Voltage	5.0	V
Ic	Collector Current - Continuous	600	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES: 1) These ratings are based on a maximum junction temperature of 150 degrees C. 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units	
		2N4402		
P _D	Total Device Dissipation Derate above 25°C	625 5.0	m₩ mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W	

PNP General Purpose Amplifie (continued

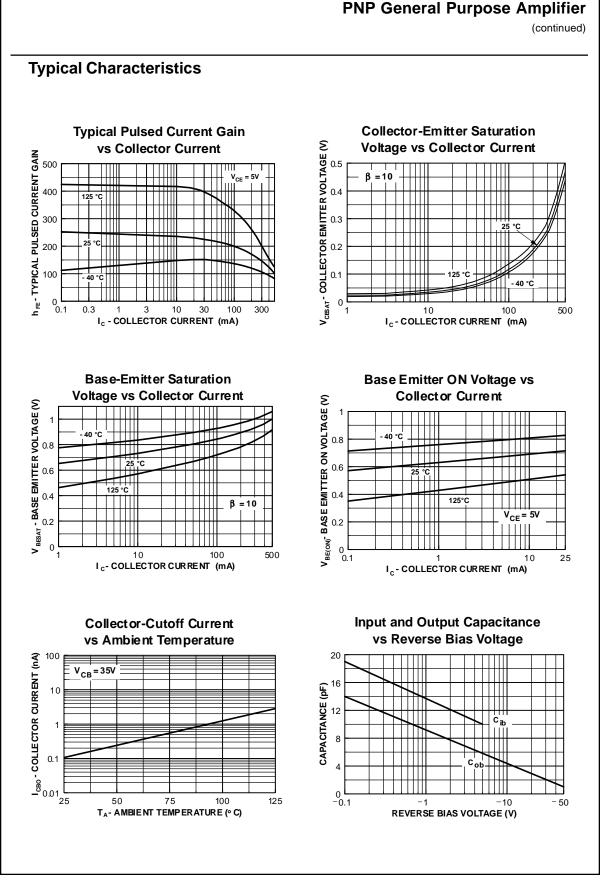
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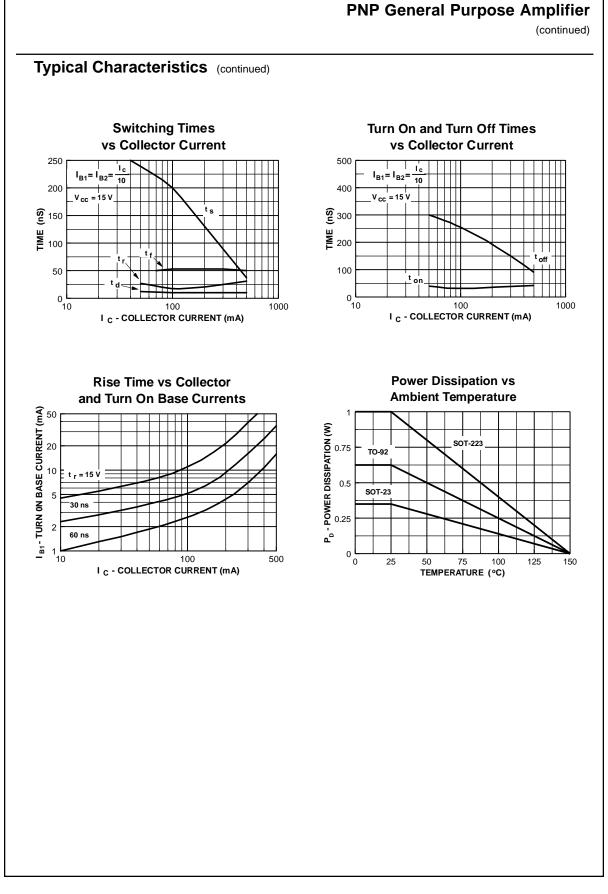
Electri	ical Characteristics TA	= 25°C unless otherwise noted			
Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0$	40		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu {\rm A}, \ I_{\rm E} = 0$	40		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{\rm E} = 100 \ \mu {\rm A}, I_{\rm C} = 0$	5.0		V
I _{CEX}	Collector Cutoff Current	$V_{CE} = 35 \text{ V}, \text{ V}_{EB} = 0.4 \text{ V}$		0.1	μA
I _{BL}	Base Cutoff Current	$V_{CE} = 35 \text{ V}, \text{ V}_{EB} = 0.4 \text{ V}$		0.1	μΑ
h _{FE}	ACTERISTICS* DC Current Gain	$V_{CE} = 1.0 \text{ V}, I_{C} = 1.0 \text{ mA}$ $V_{CE} = 1.0 \text{ V}, I_{C} = 10 \text{ mA}$ $V_{CE} = 2.0 \text{ V}, I_{C} = 150 \text{ mA}$ $V_{CE} = 2.0 \text{ V}, I_{C} = 500 \text{ mA}$	30 50 50 20	150	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{C} = 150 \text{ mA}, I_{B} = 15 \text{ mA}$ $I_{C} = 500 \text{ mA}, I_{B} = 50 \text{ mA}$		0.40 0.75	V V
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_{C} = 150 \text{ mA}, I_{B} = 15 \text{ mA}$ $I_{C} = 500 \text{ mA}, I_{B} = 50 \text{ mA}$	0.75	0.95 1.30	V V
SMALL S	IGNAL CHARACTERISTICS				
Cob	Output Capacitance	V _{CB} = 10 V, f = 140 kHz		8.5	pF
C _{ib}	Input Capacitance	$V_{EB} = 0.5 V$, f = 140 kHz		30	pF
h _{fe}	Small-Signal Current Gain	$I_{c} = 20 \text{ mA}, V_{ce} = 10 \text{ V},$ f = 100 MHz	1.5		
h _{fe}	Small-Signal Current Gain	$I_{C} = 1.0 \text{ mA}, V_{CE} = 10 \text{ V},$		250	
h _{ie}	Input Impedance	f = 1.0 kHz	0.75	7.5	kΩ
h _{re}	Voltage Feedback Ratio		0.10	8.0	x10 ⁻⁴
h _{oe}	Output Admittance		1.0	100	μmhos

SWITCHING CHARACTERISTICS

t _d	Delay Time	$V_{CC} = 30 \text{ V}, \text{ I}_{C} = 150 \text{ mA},$	15	ns
tr	Rise Time	$I_{B1} = 15 \text{ mA}, V_{BE (off)} = 2.0 \text{ V}$	20	ns
ts	Storage Time	$V_{CC} = 30 \text{ V}, \text{ I}_{C} = 150 \text{ mA},$	225	ns
t _f	Fall Time	$I_{B1} = I_{B2} = 15 \text{ mA}$	30	ns

*Pulse Test: Pulse Width $\leq 300~\mu s,~\text{Duty}~\text{Cycle} \leq 2.0\%$





PNP General Purpose Amplifier (continued) Typical Common Emitter Characteristics (f = 1.0kHz) **Common Emitter Characteristics Common Emitter Characteristics** CHAR. RELATIVE TO VALUES AT Ic= -10mA hor h_{re} h ie h_{re} and h_{oe} h _{fe} h_{re} hoe h _{fe} h ie h ie V_{CE}= -10 V I_C= -10mA T_A = 25℃ T_A = 25℃ hfe -8 -12 -16 V_{CE}- COLLECTOR VOLTAGE (V) -50 -2 -5 -10 -20 -20 I c- COLLECTOR CURRENT (mA) **Common Emitter Characteristics** I_C= -10mA h_{fe} V_{CE}= -10 V h ie h_{re} h_{oe} h_{fe} 20 0 20 40 60 8 T_A-AMBIENT TEMPERATURE (°C) 100 -20 80

PNP General Purpose Amplifier (continued)

2N4402

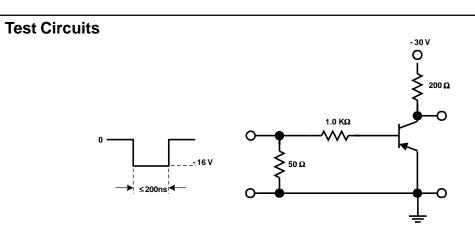


FIGURE 1: Saturated Turn-On Switching Time Test Circuit

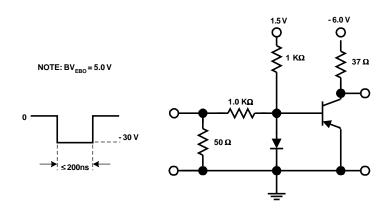


FIGURE 2: Saturated Turn-Off Switching Time Test Circuit

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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
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Product status/pricing/packaging BUY

Product	Product status	Pb-free Status	Pricing*	Package type	Leads	Packing method	Package Marking Convention**
2N4402BU	Full Production	Full Production	\$0.0275	<u>TO-92</u>	3	BULK	Line 1: 2N Line 2: 4402 Line 3: -&3
2N4402TA	Full Production	Full Production	\$0.0275	<u>TO-92</u>	3	AMMO	Line 1: 2N Line 2: 4402 Line 3: -&3
2N4402TAR	Full Production	Full Production	\$0.0275	<u>TO-92</u>	3	AMMO	Line 1: 2N Line 2: 4402 Line 3: -&3
2N4402TF	Full Production		\$0.0275	<u>TO-92</u>	3	TAPE REEL	Line 1: 2N Line 2: 4402 Line 3: -&3

Print version

		Full Production					
2N4402TFR	Full Production	Full Production	\$0.0275	<u>TO-92</u>	3	TAPE REEL	Line 1: 2N Line 2: 4402 Line 3: -&3
2N4402_D81Z	Full Production	Full Production	N/A	<u>TO-92</u>	3	TAPE REEL	Line 1: \$Y (Fairchild logo) & Z (Asm. Plant Code) & 3 (3-Digit Date Code) Line 2: 2N Line 3: 4402
2N4402_J14Z	Full Production	Full Production	N/A	<u>TO-92</u>	3	BULK	Line 1: \$Y (Fairchild logo) & Z (Asm. Plant Code) & 3 (3-Digit Date Code) Line 2: 2N Line 3: 4402

* Fairchild 1,000 piece Budgetary Pricing
** A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please contact a <u>Fairchild distributor</u> to obtain samples

Ø Indicates product with Pb-free second-level interconnect. For more information click here.

Package marking information for product 2N4402 is available. <u>Click here for more information</u>.

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Models

Package & leads	Condition	Temperature range Software version		Revision date		
PSPICE						
TO-92-3	Electrical	25°C	N/A	N/A		

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Qualification Support

Click on a product for detailed qualification data

Product	
2N4402BU	
2N4402TA	
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2N4402TAR
2N4402TF
2N4402TFR
2N4402_D81Z
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